


Article

Research on ZVS Phase-Shifted Full-Bridge Broadband Inverter Based on Auxiliary Current Source

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Abstract: Phase-shifted full-bridge topologies are widely used in medium- and high-power DC/DC converters due to their small size and high switching frequency. However, there are few studies on the application of broadband inverters. In the traditional phase-shift full-bridge inverter with a fully resonant load, the problem of current commutation which leads to hard switching is often encountered, to overcome such an issue, an auxiliary current source network is introduced to realize the zero-voltage turn-on of the lagging bridge arm. The working modes of the converter are analyzed in detail, and the parameters of the auxiliary current source network are designed. The simulation verification is carried out by MATLAB/Simulink in a wide frequency range from 10 kHz to 500 kHz. Finally, an experimental circuit board is designed, and the experimental results show that the topology can achieve soft switching in a frequency range from 10 kHz to 200 kHz and has a certain applicability.

Keywords: auxiliary current source; broadband; phase-shifted full-bridge inverter; zero voltage switch



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1. Introduction

In recent years, with the rapid development of power electronics technology, various electrical equipment are increasingly inseparable from switch converters. The development of this technology also puts forward higher requirements on the performance, weight, volume, efficiency and reliability of the switch power supply. If the voltage and current waveforms overlap during the turn-on and turn-off of the switching device, it is called hard switching. As the operating frequency increases, the number of hard switching per unit time increases, and the loss of the inverter increases accordingly [1–3]. To reduce the loss, soft switching technology emerges as the time required. Many scholars have successively proposed resonant converter (RC), quasi-resonant converter (QRC) and multi-resonant converter (MRC) [4–6], which realize the zero-voltage soft switching or zero-current soft switching of the transistors, reduce the switching loss, improve the efficiency of the converter, greatly improve the switching frequency, and reduce the volume and weight.

The full-bridge inverter circuit is the most widely used topology in single-phase inverter power supplies, with the advantages of a simple, symmetrical structure and a flexible, simple control method. Using the full-bridge high-frequency inverter topology in the high-frequency power supply can obtain higher efficiency. According to the different turn-on signals of the switching devices, the common control methods of the full-bridge converters include bipolar control methods, finite unipolar control methods and phase-shift control methods. In the phase-shifted full-bridge control method, the current and voltage stress of the switching device is small, which is easier to realize soft switching, the load circuit itself has a good filtering effect, and the switching frequency remains unchanged, avoiding the problem of frequency runaway. Since the phase-shift control method has the above advantages, this paper chooses the phase-shift control method [7].

At present, the full-bridge circuit using phase-shift control has been deeply studied in various situations: in biological applications, the article [8] proposed a high-frequency

high-voltage composite pulse generator, in which eight switches are connected in series on one bridge arm. To study the mechanism of tumor ablation under the high-frequency composite pulse and reduce the number and intensity of muscle contractions, the transistor generates a composite pulse with a frequency of 2 MHz and a pulse amplitude of 3 kV. In terms of induction heating, the article [9,10] uses the principle of induction heating to propose a power control scheme of a series resonant full-bridge inverter to heat cookware at a frequency of 35 kHz. The article [11] presents a novel high-performance high-frequency soft-switching inverter for induction heating applications. For multiple load induction heating applications, the article [12] proposed a three-switch inverter composed of only three switches and two split capacitors. Asymmetric duty cycle control is used to obtain independent control over two loads simultaneously. In addition to the structure of the inverter, research on the control method is also essential. The article [13] proposed a new control method for induction cookware applications with a series resonant inverter, which simplified the design of the control circuit. However, this method used a sampling circuit, which could bring some interference to the experimental results. In the article [14], an extended series-resonant inverter (SRI) with the output current control based on the pulse-density-modulation (PDM) control technique has been presented. The disadvantage of the PDM control technique is that it can lead to different output current amplitudes. Due to the soft switching characteristics of the full load range, the inverter has low EMI noise and high efficiency, which can be suitable for higher frequency induction heating applications. In terms of wireless energy transmission, in the article [15], a magnetically coupled resonant wireless transmission method is proposed, and a 1.2 kW/48 V prototype is built by taking advantage of the phase-shifted full-bridge soft-switching technology, which not only realizes the soft-switching of the full-bridge circuit but also improves the transmission efficiency of the wireless transmission system.

Of the above applications, most of them are designed for a single switching frequency. Less research has been done in applications where a broadband switching frequency is required, such as driving Helmholtz coils for magnetic field probe correction [16]. When the phase-shifted full-bridge inverter is connected to the RLC series resonant load, the current in the switching device sometimes flows in the reverse direction. At this time, the turn-off signal cannot effectively turn off the switching device, resulting in hard switching. The topology of a ZVS phase-shifted full-bridge inverter based on an auxiliary current source is used to achieve soft switching by injecting a current into the switching devices to charge their parallel capacitors. The relationship between the parameters of the auxiliary current source network and the frequency band used for soft switching is studied.

The remainder of this paper is organized as follows. The inverter circuit and its working modes are analyzed in Section 2. In Sections 3 and 4, a simulation model is built and analyzed, and a 30 V input and 18.2 V/1.2 A output prototype was designed and tested to verify the feasibility of this topology. Finally, the conclusion is drawn in Section 5.

2. Full-Bridge Inverter Circuit and Its Working Modes Analysis

2.1. Full-Bridge Inverter Topology

The circuit topology used in this paper is shown in Figure 1. The circuit consists of a typical full-bridge inverter circuit and an auxiliary injection current source. For the Full-bridge inverter circuit, V_{DC} is the DC input voltage source, Q_1 – Q_4 are power MOSFETs, Q_1 and Q_3 form the leading bridge arm, Q_2 and Q_4 form the lagging bridge arm, and the two transistors on the same bridge arm cannot be simultaneously conducted, otherwise, it will cause a short circuit to the DC voltage source, so that the current flowing through the transistors is too large, and the components will be burned. L , C and R are resonant inductance, resonant capacitance and resistive load, respectively. During operation, L and C resonate in series, so that the load current presents a sine wave. For the auxiliary current source [17], the network consists of auxiliary inductance L_a , auxiliary diodes D_{a1} , D_{a2} and auxiliary capacitors C_{a1} , C_{a2} . The auxiliary inductor L_a is connected to the midpoint of the

lagging bridge arm and the midpoint of the bridge arm formed by the auxiliary diodes D_{a1} and D_{a2} .

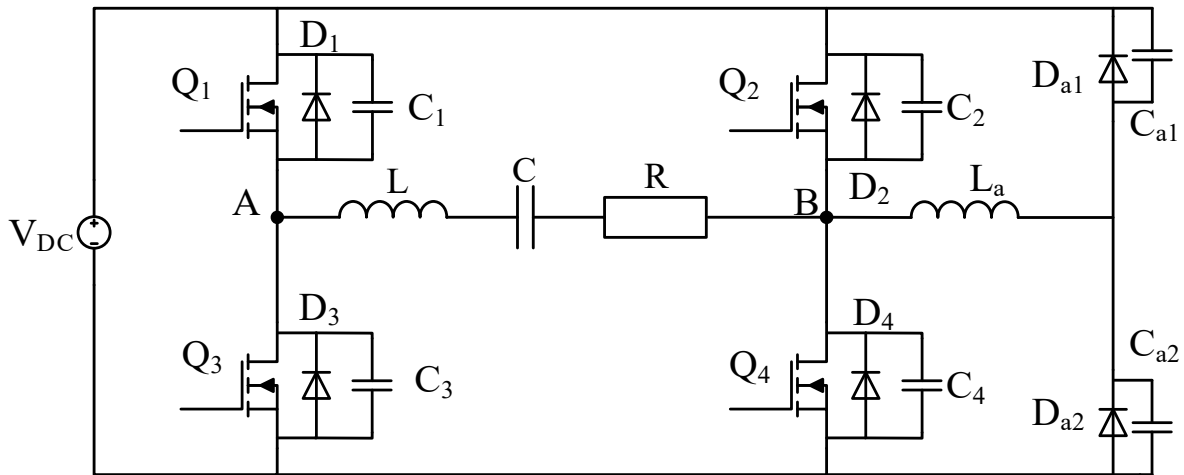


Figure 1. Diagram of Full bridge inverter structure.

The drive signals of four switches Q_1 – Q_4 , the waveforms of the AB port voltage u_{AB} , and the load current i_o are shown in Figure 2. The main waveform diagram of the auxiliary current source network is shown in Figure 3. It can be seen that the conduction signals of the switches on the same bridge arm are 180° complementary (to ensure soft switching, a certain dead time is set), the difference between the driving signals of the switches at the diagonal position, i.e., the phase shift angle, and the output voltage can be adjusted by adjusting the size of the phase shift angle θ .

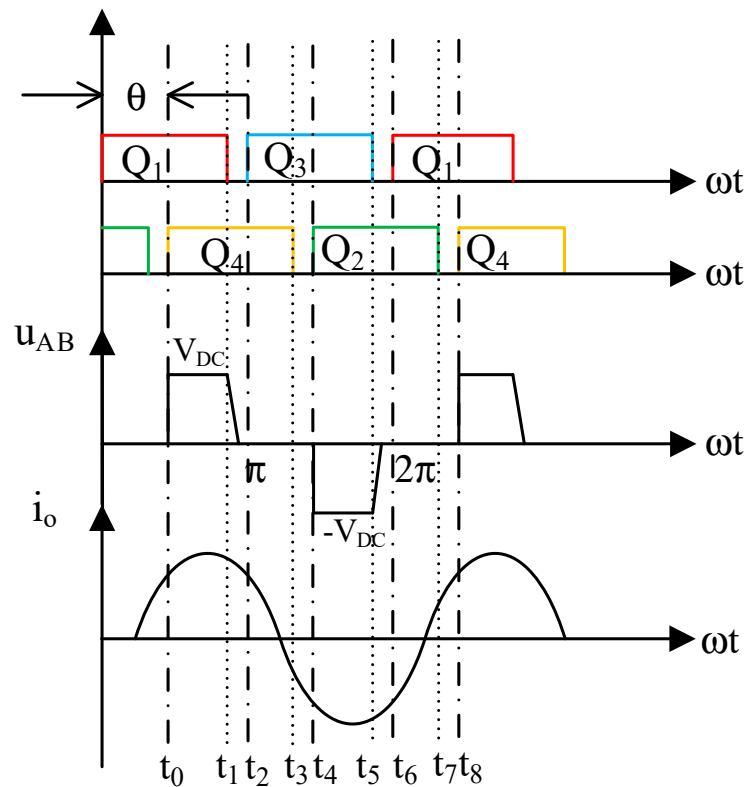


Figure 2. Phase-shift control signal and load voltage and current waveforms.

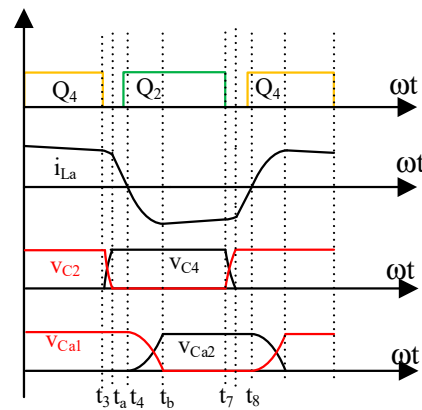


Figure 3. Main waveforms of the auxiliary current source network.

Within one cycle, the expression for the output port voltage is:

$$u_{AB} = \begin{cases} 0, & 0 < \omega t < \theta, \pi < \omega t < \pi + \theta \\ V_{DC}, & \theta < \omega t < \pi \\ -V_{DC}, & \pi + \theta < \omega t < 2\pi \end{cases} \quad (1)$$

Fourier decomposition of this voltage waveform yields:

$$u_{AB} = \sum_{n=1}^{\infty} \frac{4V_{DC}}{n\pi} \cos \frac{n\theta}{2} \sin(n\omega t), n = 1, 3, 5 \dots \quad (2)$$

Then, its fundamental component is:

$$u_{AB1} = \frac{4V_{DC}}{\pi} \cos \frac{\theta}{2} \sin(\omega t) \quad (3)$$

If ω is the resonant angular velocity of the LC load, i.e.,

$$\omega = \omega_0 = \frac{1}{\sqrt{LC}} \quad (4)$$

Then, at this angular velocity, the RLC load can be regarded as a purely resistive load. So, the current i_o flowing through the load is:

$$i_o = \frac{4V_{DC}}{R\pi} \cos \frac{\theta}{2} \sin(\omega t) \quad (5)$$

2.2. Circuit Working Modes Analysis

When the load works at the resonant frequency, the waveforms of the port voltage u_{AB} and the load current i_o are shown in Figure 2 [18]. The waveform analysis of the circuit topology shown in Figure 1 is presented, and the following assumptions are made to facilitate the analysis:

1. All switches and diodes are ideal devices. The conduction voltage drop of the diode is v_d .
2. All inductors and capacitors are ideal devices.
3. $C_1 = C_2 = C_3 = C_4 = C_p, C_{a1} = C_{a2} = C_a$.

Switching mode 1 (t_0-t_1): At time t_0 , Q_4 is turned on. The voltage of port AB is the power supply voltage V_{DC} , and the current i_o flows from the power supply through Q_1 , resonant inductor L , resonant capacitor C , resistor R and Q_4 , and finally returns to the power supply, and this mode lasts until time t_1 . The injection current i_{La} flows through the

auxiliary diode D_{a2} , the auxiliary inductance L_a , and the switch Q_4 to form a loop, which corresponds to Figure 4a.

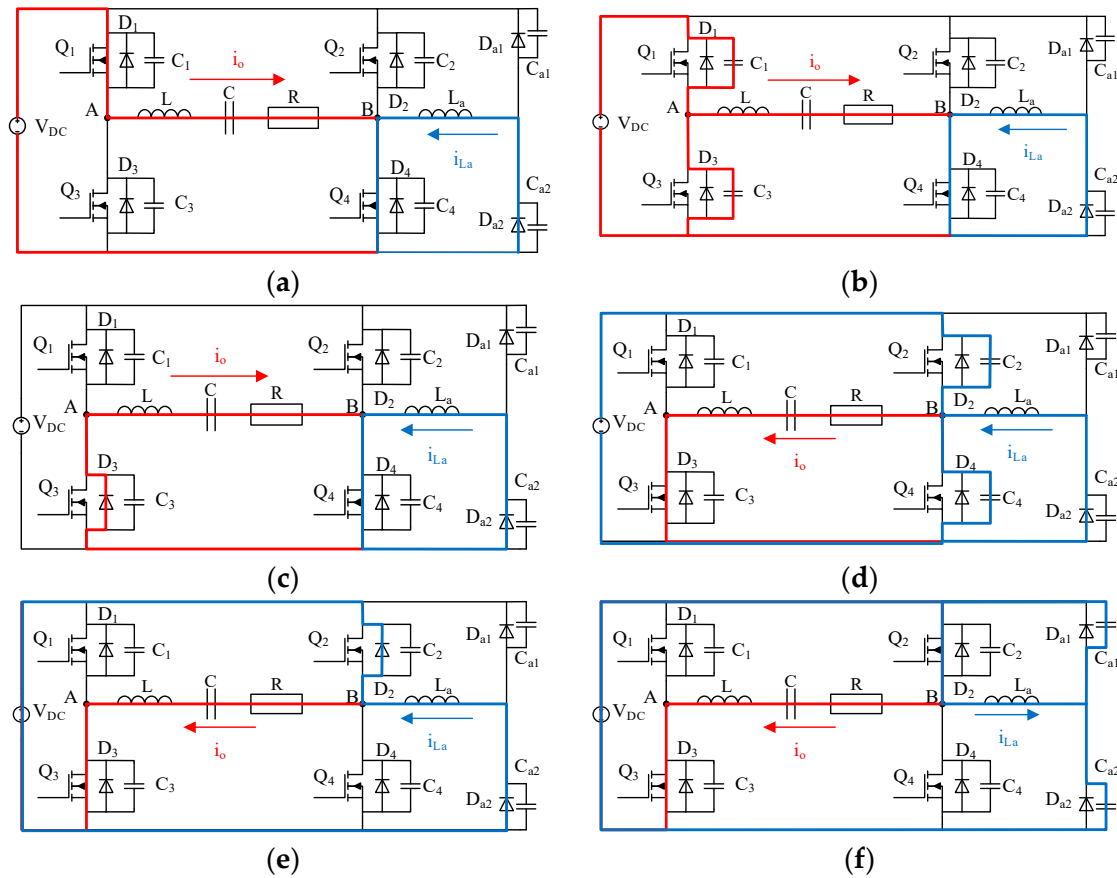


Figure 4. Current path diagrams for various switching modes. (a–f) Switching mode 1–6.

Switching mode 2 (t_1 – t_2): At time t_1 , Q_1 is turned off. Due to the freewheeling effect of the resonant inductor L , the current will be transferred from Q_1 to the capacitors C_1 and C_3 of the switches, charging C_1 , whereas discharging C_3 at the same time. The voltage of point A will gradually decrease. When it drops to zero, D_3 will be turned on naturally, and then the turn-on signal of Q_3 will come at time t_2 , realizing the zero-voltage turn-on of Q_3 . The injected current keeps the path of the previous mode, which corresponds to Figure 4b.

During the charging process of C_1 , by KVL, there are:

$$v_{C1} + v_{C3} = V_{DC} \tag{6}$$

The derivative of the voltage is:

$$\frac{dv_{C1}}{dt} = -\frac{dv_{C3}}{dt} \tag{7}$$

Because $i_C = C \frac{dv_C}{dt}$, there are:

$$i_{C1} = i_{C3} = \frac{1}{2}i_o \tag{8}$$

Because in switching mode 2, the amount of current change is small, it may be considered that the current during this period is constant, and its value is the current value at time t_2 . Then, there are:

$$i_{C1}(t_2) = i_{C3}(t_2) = \frac{1}{2}i_o(t_2) = \frac{2V_{DC}}{R\pi} \cos \frac{\theta}{2} \sin \frac{\theta}{2} \tag{9}$$

Switching mode 3 (t_2-t_3): Q_3 is turned on at time t_2 . Although Q_3 is in on state at this time, the current does not flow through Q_3 , but freewheels through D_3 , which is naturally turned on. Since Q_4 is also in on state, the voltage across port AB is zero, and this mode lasts until time t_3 . In this switching mode, the load current changes from positive to negative. The injected current path continues to remain unchanged. This mode corresponds to Figure 4c.

Switching mode 4 (t_3-t_a): Q_4 is turned off at time t_3 . Since the current has commutated at this moment, if there is no injection current i_{La} , the load current will flow through D_4 for freewheeling, realizing zero-voltage turn-off of Q_4 . However, in this mode, no current flows through capacitor C_4 , which cannot be charged, so the voltage at point B remains zero. When Q_2 is turned on, the voltage at point B is forcibly pulled high, and the zero-voltage turn-on of the lagging bridge arm is not realized. Additionally, when 1/2 of the injected current i_{La} at this moment is greater than the load current at this moment, C_4 can be charged, creating conditions for the soft switching of the lagging bridge arm. The injection current path is shown in Figure 4d.

Note the magnitude of the injected current $i_{La}(t_3)$ at time t_3 as i_{Lal} . When charging and discharging the capacitor, it is approximately considered that the current keeps i_{Lal} unchanged. Then, in the process of charging and discharging, there are:

$$0.5(i_{Lal} - i_o) = C_p \frac{dv_{C4}}{dt} \quad (10)$$

Then, the charging and discharging duration t_{3a} is:

$$t_{3a} = \frac{C_p V_{DC}}{0.5(i_{Lal} - i_o)} \quad (11)$$

If the time is less than the dead time, the soft switching of the lagging bridge arm can be guaranteed.

Switching mode 5 (t_a-t_4): At time t_a , after charging and discharging the lagging bridge arm capacitor by the injected current in the previous mode, the voltage at point B rises to the power supply voltage, and D_2 is naturally turned on. The main circuit and the flow of the injected current are shown in Figure 4e. Since the voltage across the auxiliary inductor L_a is the power supply voltage at this time, the injection current i_{La} will decrease with the slope of $-V_{DC}/L_a$, and the injection current will decrease to zero for t_{a4} :

$$t_{a4} = \frac{L_a i_{Lal}}{V_{DC}} \quad (12)$$

Switching mode 6 (t_4-t_b): At the moment of t_4 , the switch Q_2 is turned on. Since its body diode D_2 is naturally turned on, it leads to zero-voltage turn-on. The main circuit and the flow of the injected current are shown in Figure 4f. The injected current is commutated, the auxiliary inductor L_a and the auxiliary capacitors C_{a1} and C_{a2} work in resonance, i_{La} charges C_{a2} and discharges C_{a1} at the same time.

The injected current i_{La} and the voltages of C_{a1} and C_{a2} in this period are:

$$i_{La}(t) = \frac{V_{DC}}{Z_a} \sin \omega_a(t - t_4) \quad (13)$$

$$v_{Ca1}(t) = V_{DC} \cos \omega_a(t - t_4) \quad (14)$$

$$v_{Ca2}(t) = -V_{DC} \cos \omega_a(t - t_4) + V_{DC} \quad (15)$$

where $\omega_a = 1/\sqrt{2L_a C_a}$, $Z_a = \sqrt{L_a/(2C_a)}$. The time required to charge the auxiliary capacitor C_{a2} is:

$$t_{4b} = \frac{\pi}{2} \sqrt{2L_a C_a} \quad (16)$$

At time t_b , the injected current is:

$$i_{La}(t_b) = \frac{V_{DC}}{Z_a} \quad (17)$$

The injected current at this moment is denoted as i_{Lah} . As can be seen from Figure 3, the slope of the auxiliary inductor current changes in a sinusoidal manner, so the auxiliary inductor voltage will not have a large mutation.

After time t_b , the auxiliary diode D_{a1} is naturally turned on, and the injection current i_{La} flows through the switch Q_2 , the auxiliary inductance L_a , and the auxiliary diode D_{a1} to form a loop. Due to the conduction voltage drop v_d of the diode, the auxiliary inductor current will gradually decrease, and the slope of the current decrease is v_d/L_a . Until the time t_7 , the switch Q_2 is turned off, and the second half cycle begins, and the analysis is similar to the first half cycle. In order to save space, it will not be described in detail here.

From the above analysis, it can be concluded that:

1. To realize the soft switching of the leading bridge arm, it is necessary to ensure that the current flowing through the capacitor can charge the capacitor to the power supply voltage V_{DC} within the dead time. According to $i_C = C \frac{dv_C}{dt}$, combined with (9), the time required to charge the capacitor to the power supply voltage V_{DC} can be obtained as:

$$t_r = \frac{C_p R \pi}{\sin \theta} \quad (18)$$

This time is less than the dead time to ensure soft switching.

2. To realize the soft switching of the lagging bridge arm, it is necessary to ensure that the charging and discharging time t_{3a} of the lagging bridge arm is less than the dead time.
3. The maximum value i_{Lah} of the auxiliary inductor current i_{La} is only related to the parameters of the DC voltage source and the auxiliary network, $i_{Lah} = \frac{V_{DC}}{Z_a} = \frac{V_{DC}}{\sqrt{L_a/(2C_a)}}$, therefore, as long as the parameters of the auxiliary network are determined, the magnitude of the current injected into the desired bridge arm can be determined.
4. The voltage stress of the auxiliary capacitor is the DC voltage source voltage V_{DC} .
5. The voltage stress of the auxiliary diode is V_{DC} and its current stress is i_{Lah} .
6. When Q_4 (or Q_2) is off, the auxiliary inductor current i_{La} flows into (or out of) node B. Its amplitude is:

$$|i_{Lal}| = \frac{V_{DC}}{\sqrt{L_a/(2C_a)}} - \frac{v_d}{L_a} t_c \quad (19)$$

where $t_c = \frac{1}{2f} - (t_{3a} + t_{a4} + t_{4b})$.

2.3. Applicable Frequency Range

When the frequency decreases, the current i_{Lal} injected by the auxiliary current source decreases due to the extended time that the conduction voltage drop of the auxiliary diode acts on the auxiliary inductor. When the frequency increases, the switch Q_2 (or Q_4) will be turned off when the auxiliary capacitor C_{a2} is fully charged (or discharged), so that the injection current is maximized. Therefore, as long as the injection current i_{Lal} and the maximum current i_{Lah} are slightly larger than i_{Lal} , a certain frequency range can be found, so that the parameters of the auxiliary current source designed in this paper can achieve soft switching within this range.

Calculation of the lowest frequency: When the injected current drops from i_{Lah} to i_{Lal} , the corresponding switch will act. According to the current falling time, resonance time and linear falling time, the lowest frequency can be calculated. Since i_{Lah} and i_{Lal} are given, the current falling time t_c can be calculated:

$$t_c = (i_{Lah} - i_{Lal}) \frac{L_a}{v_d} \quad (20)$$

The lowest frequency f_L can be calculated by substituting (20) into (19):

$$f_L = \frac{1}{2(t_{01} + t_{12} + t_{23} + t_c)} \quad (21)$$

Calculation of the highest frequency: When the resonance of the auxiliary inductor and capacitor is completed, the corresponding switch will act when the injected current is the largest. From the resonance time and the linear falling time, the highest frequency f_H can be calculated:

$$f_H = \frac{1}{2(t_{01} + t_{12} + t_{23})} \quad (22)$$

Therefore, for the auxiliary inductance L_a , the auxiliary capacitance C_a can be calculated from i_{Lah} and (17). Then, the applicable frequency range of soft switching corresponding to the parameters of the auxiliary current source can be obtained.

3. Simulation Results Analysis

3.1. Simulation Parameter Setting

The DC voltage source used in the simulation is $V_{DC} = 30$ V, the load inductance L is set to 1 mH, and the load resistance R is 15 Ω . The load capacitance C working in the resonance state can be determined by (4):

$$C = \frac{1}{4\pi^2 f^2 L} \quad (23)$$

Set the dead time to 100 ns. To realize the adjustable ability of the load current, the phase shift angle θ needs a certain adjustment range. In this paper, the range of the phase shift angle θ is set to 10° – 170° . According to (18), when the switch Q_1 is turned off, the time required for C_1 to charge to the power supply voltage is:

$$t_r = \frac{C_p R \pi}{\sin \theta} = \frac{15\pi}{\sin \theta} C_p \quad (24)$$

In order to ensure that the phase shift angle θ is in the range of 10° – 170° , the leading bridge arm can achieve soft switching, it is necessary to take θ 10° (or 170°) when the calculated charging time t_r is less than the dead time 100 ns. Setting $C_p = 350$ pF in this paper. In this case, the load current when switch Q_1 is turned off is 0.22 A.

For the lagging bridge arm, according to Figure 2, the current magnitude of the load current i_o when Q_4 is turned off $|i_o(t_3)|$ is slightly smaller than the current magnitude $|i_o(t_4)|$ when Q_2 is turned on. From the symmetry of the sine function and (9), the magnitude of the reverse load current $|i_o(t_3)|$ when Q_4 is turned off can be calculated:

$$|i_o(t_3)| \approx |i_o(t_4)| = |i_o(t_2)| = \frac{2V_{DC}}{R\pi} \sin \theta \quad (25)$$

To ensure that the injected current can compensate for the reverse load current within the required phase shift angle and to charge and discharge the parallel capacitor of the lagging bridge arm, the maximum reverse load current is required when Q_4 is turned off, i.e., the phase shift angle θ is 90° . The maximum reverse load current when Q_4 is turned off is obtained by (25) as 1.27 A. It has been deduced before that the minimum load current required for charging and discharging the parallel capacitor of the switch is 0.22 A, with a certain margin, the i_{Lal} of the injected current source is set to 2 A.

Taking the maximum injection current i_{Lah} as 3 A, and using (11), (17) and their corresponding analysis, there are:

$$t_{3a} = \frac{C_p V_{DC}}{0.5i_{Lal} - i_o} \leq 100 \text{ ns} \quad (26)$$

$$C_a = \frac{i_{Lah}^2}{2V_{DC}^2} L_a \quad (27)$$

For the calculation of the lowest and highest frequencies, from the parameters given by the simulation and (21), (22), the relationship between the lowest frequency, the highest frequency and the auxiliary inductance can be obtained as:

$$f_L = \frac{1}{2(2 \times 10^{-9} + 1.132L_a)} \quad (28)$$

$$f_H = \frac{1}{2(2 \times 10^{-9} + 0.223L_a)} \quad (29)$$

The relationship between the two frequencies and the auxiliary inductance is shown in Figure 5, it can be seen that the smaller the auxiliary inductance, the higher the frequency range in which the auxiliary current source can achieve soft switching. However, the minimum frequency at which a smaller auxiliary inductor can achieve soft switching is still very large. Therefore, to achieve the widest possible range of soft switching, it is necessary to use multiple sets of auxiliary inductor-capacitor parameters.

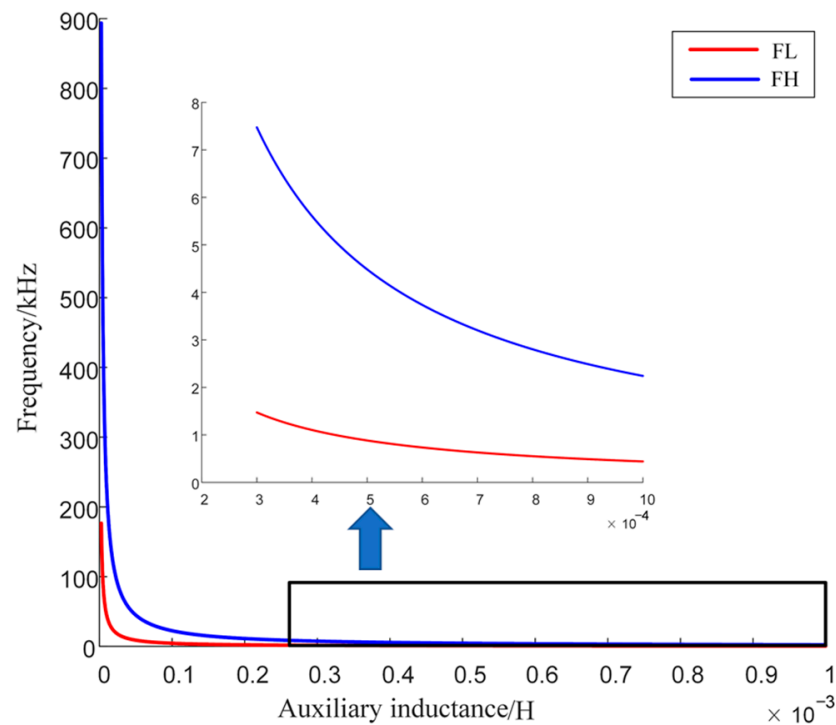


Figure 5. Relationship between frequency and auxiliary inductance.

In order to realize the soft switching in the frequency range of 10 kHz–500 kHz, the selected auxiliary inductance and capacitance parameters are shown in Table 1. For example, when the LC parameter of number 1 is selected, soft switching can be realized in the range of 10–50 kHz, which is the advantage of the auxiliary circuit. By changing the number of the auxiliary circuit, the frequency range of the soft switching can be broadened.

Table 1. Auxiliary current source parameters and corresponding frequency ranges.

Number	L_a (μH)	C_a (nF)	Lowest Frequency f_L (kHz)	Highest Frequency f_H (kHz)
1	44.18	220.9	9.99	50.80
2	8.69	43.47	50.80	257.66
3	2.78	13.9	158.78	803.94

3.2. Simulation Circuit and Results Analysis

According to the parameters in the previous section, the simulation model of the phase-shifted full-bridge inverter is built using MATLAB/Simulink simulation software, as shown in Figure 6.

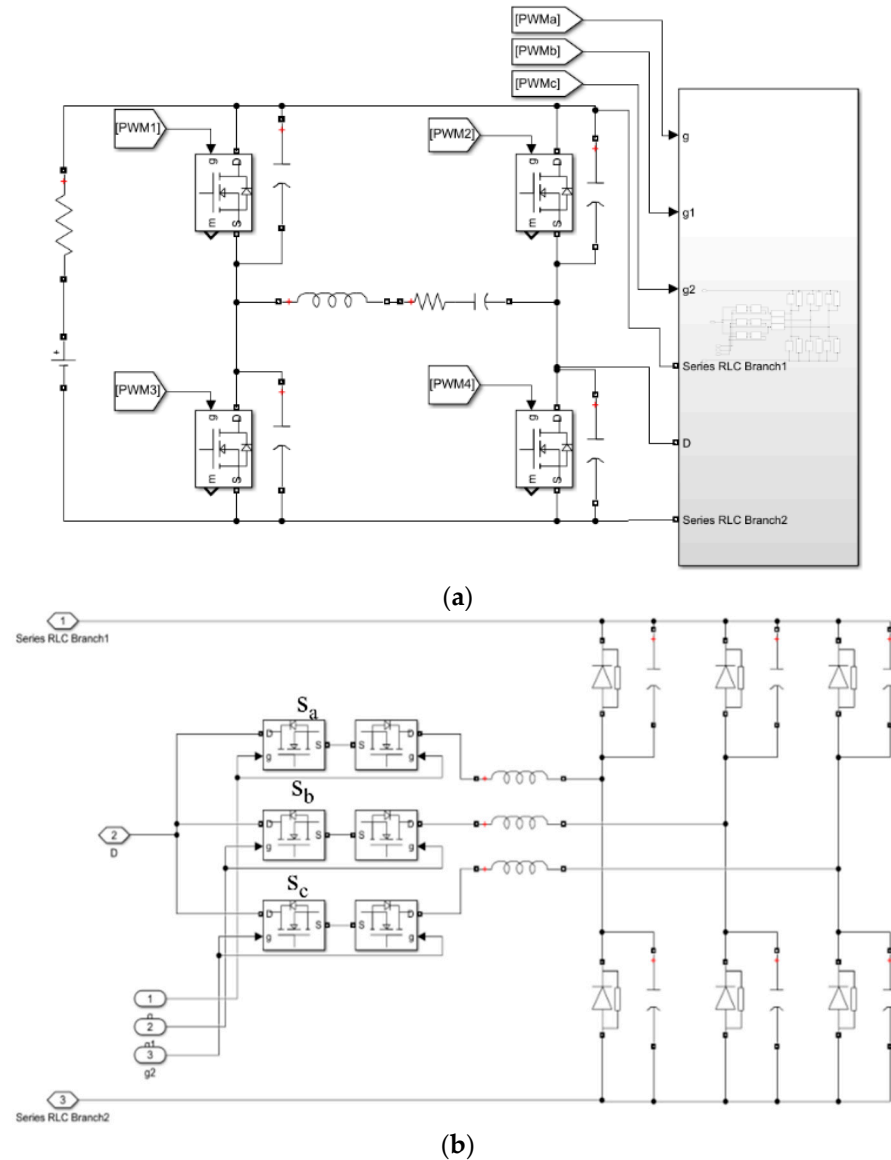


Figure 6. Simulation circuit model. (a) Main circuit diagram; (b) Auxiliary current source network.

In this circuit, switches connected in series are used to realize the access of the corresponding auxiliary current source. Once the switching frequency is determined, three switch sets S_a , S_b and S_c are used to select appropriate auxiliary circuits to help achieve soft switching. When the switching frequency is in the range of 10 kHz to 50.80 kHz, only the switch set S_a corresponding to the auxiliary current source of serial number 1 is turned on, so that it is connected to the circuit; when the switching frequency is in the range of 50.80 kHz to 257.50 kHz), only the switch set S_b is turned on to involve the auxiliary current source of serial number 2. When the switching frequency is 257.50 kHz to 500 kHz, only the switch set S_c is turned on, and the auxiliary current source of number 3 is connected to the circuit. The switching frequency of the inverter remains unchanged during operation, so the state of the switch sets S_a , S_b and S_c also remains unchanged. As the bidirectional switch controlling the auxiliary circuit is always on, the loss is almost only conduction loss,

which is a small part of the total loss. By selecting the connected auxiliary current sources according to the frequency range, a broadband zero-voltage soft-switching can be achieved.

Taking 90° phase shift angle as an example, set the simulation parameters as follows: switching frequency $f = 10$ kHz, dead time 100 ns, DC voltage source $V_{DC} = 30$ V, voltage source series resistance $R_s = 0.01 \Omega$, load inductance $L = 1$ mH, load resistance $R = 15 \Omega$, load capacitance $C = 253.3$ nF, the parallel capacitance of the switch $C_p = 350$ pF.

Without the auxiliary current source network, the load voltage and current waveforms are shown in Figure 7a; the trigger signals PWM1, PWM3 of the switch Q_1 and the drain-source voltage waveform are shown in Figure 7b; the trigger signals PWM2 and PWM4 of the switches Q_2, Q_4 , and the drain-source voltage waveform of the switch Q_4 are shown in Figure 7c.

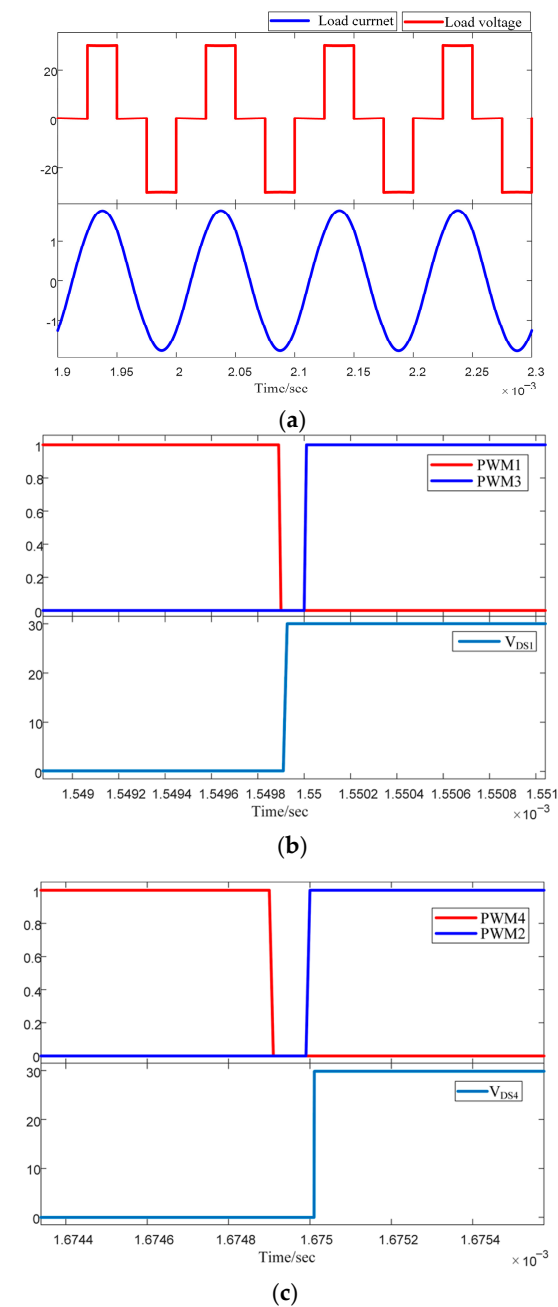


Figure 7. Main waveforms without auxiliary current source. (a) Load voltage and current waveform; (b) Q_1Q_3 trigger signal and Q_1 drain-source voltage waveform; (c) Q_2Q_4 trigger signal and Q_4 drain-source voltage waveform.

As can be seen, when switch Q_1 is turned off, its drain-source voltage gradually increases and rises to the power supply voltage V_{DC} before Q_3 is turned on, which can realize the soft turn-on of Q_3 . As for the switches Q_2 and Q_4 , since the current has been commutated, the current cannot charge the capacitor when Q_4 is turned off, and soft switching cannot be realized, which is consistent with the previous analysis. The output power is calculated as 23.59 W, and the efficiency is 98.6%, thus, the simulation and experiment are carried out at a low power level.

When connected to the auxiliary current source network, the load voltage and current waveforms are shown in Figure 8a; the trigger signals PWM1, PWM3 of the switch Q_1 , Q_3 , and the drain-source voltage waveform of the switch Q_1 are shown in Figure 8b; the voltage waveform of the auxiliary capacitor and the current waveform injected by the current source is shown in Figure 8c; the trigger signals PWM2 and PWM4 of the switch Q_2 , Q_4 , and the drain-source voltage waveform of the switch Q_4 are shown in Figure 8d.

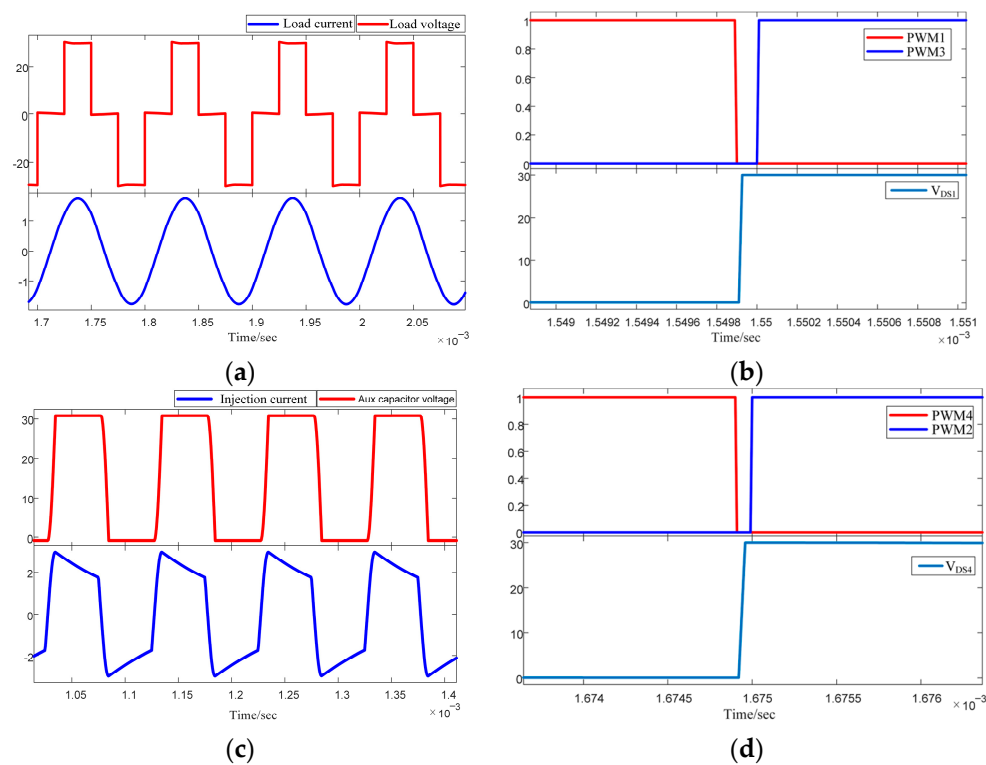


Figure 8. Main waveforms with auxiliary current source. (a) Load voltage and current waveform; (b) Q_1 – Q_3 trigger signal and Q_1 drain-source voltage waveform; (c) Voltage waveform of the auxiliary capacitor and the auxiliary current source injection current waveform; (d) Q_2 – Q_4 trigger signal and Q_4 drain-source voltage waveform.

As can be seen from the figure, since the auxiliary current source is connected, the commutated current is compensated by the injected current and charges the capacitor connected in parallel with the switches. Therefore, when Q_4 is turned off, its drain-source voltage can increase, which creates conditions for soft turn-on of Q_2 . By using the auxiliary current source, the zero-voltage turn-on and turn-off of the four switches can be realized, which ensures the reliable operation of the switches. The voltage stress of the auxiliary capacitor is the voltage of the source, 30 V, the current stress of the auxiliary inductance is $i_{L_{ah}}$, 3 A, which is in accordance with the previous analysis. The output power can be calculated as 23.33 W; however, the efficiency is 84.7%. It is the auxiliary current source that adds the source current, which leads to the input power rising and the efficiency decreasing.

Since the leading bridge arm has been soft-switched by the load current, the following studies are related to the waveforms of the lagging bridge arm. When the switching

frequency is increased to 50 kHz, the load capacitance working in the resonance state is calculated by (23) to be 10.13 nF, and the relevant waveforms of the injected current and the lagging bridge arm are shown in Figure 9.

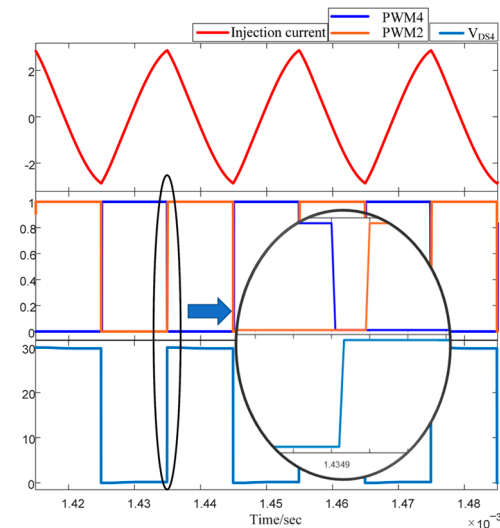


Figure 9. The main waveforms of the injected current and lagging bridge arm at 50 kHz with auxiliary current source.

As the frequency increases, the drop time t_c of the injected current becomes shorter, and the drain-source voltage of the switch Q_4 can be charged to the power supply voltage V_{DC} before the switch Q_2 conduction signal, realizing a soft switching of the lagging bridge arm.

When the switching frequency is 100 kHz and 500 kHz, the injected current and the related waveforms of the lagging bridge arm are recorded, respectively, as shown in Figure 10.

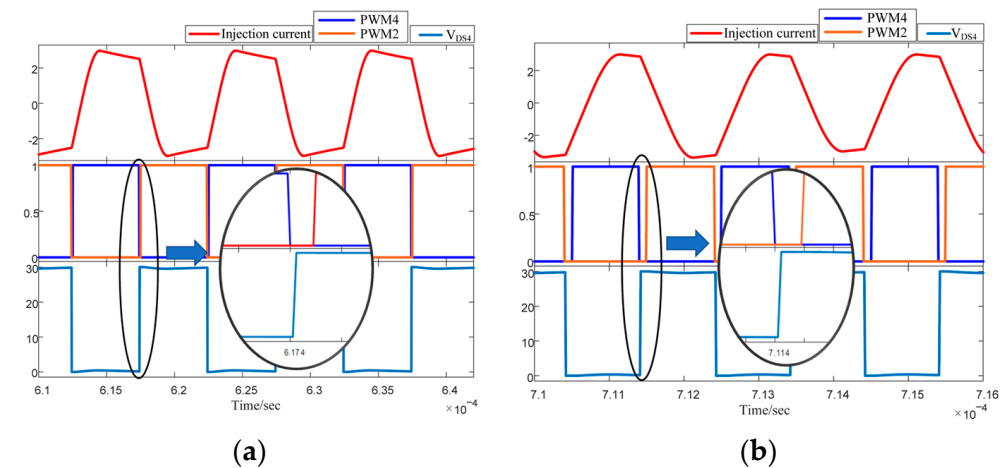


Figure 10. The main waveforms of the injected current and lagging bridge arm at 100 kHz and 500 kHz. (a) The main waveforms of the lagging bridge arm and the injected current at 100 kHz; (b) The main waveforms of the lagging bridge arm and the injected current at 500 kHz.

By switching the network parameters of the auxiliary current source with different numbers, soft switching with a switch frequency range of 10 kHz–500 kHz can be realized.

In order to determine the range of the phase shift angle corresponding to each frequency band, the range of the load current waveform magnitude when soft switching can be achieved at each frequency is now measured and recorded in Figure 11.

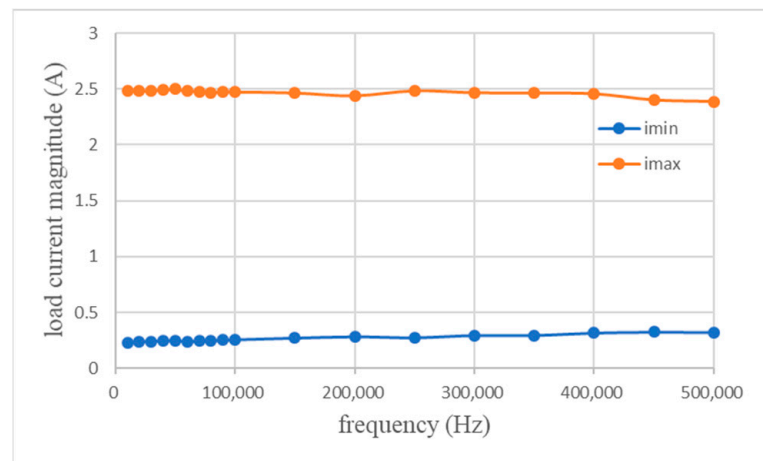


Figure 11. Range of load current amplitudes for soft switching at each frequency.

It can be seen from the figure that in the frequency range of 10 kHz–500 kHz, the magnitude of the load current that can achieve soft switching is 0.23 A–2.5 A, which is converted to a phase shift angle of 10° – 170° , and that is consistent with the previous analysis.

3.3. Loss and Efficiency Analysis

The losses of the inverter mainly include losses of the switches and the auxiliary inductors. For losses of the full bridge switches, which can be distributed in turn-on losses, turn-off losses and conduction losses. In the proposed inverter, ZVS operation has been achieved in all four switches, the losses of the turn-on and the turn-off are insignificant and can be eliminated [19]. The conduction losses of the full bridge switches can be calculated according to (30):

$$P_{loss_fbcon} = 2R_{fb_on}(I_{13RMS}^2 + I_{24RMS}^2) \quad (30)$$

where R_{fb_on} is the ON-state resistance of MOSFETs, I_{13RMS} and I_{24RMS} are the RMS current of the leading and lagging bridge, respectively.

There are only conduction losses for the bidirectional switches, which can be calculated according to (31):

$$P_{loss_bicon} = 2R_{bi_on}I_{laRMS}^2 \quad (31)$$

where R_{bi_on} is the ON-state resistance of the bidirectional switches, I_{laRMS} is the RMS current of the injected current.

For the losses of the auxiliary inductors, which can be derived by (32):

$$P_{loss_ind} = I_{laRMS}^2 R_{La} \quad (32)$$

where R_{La} is the ESR of the auxiliary inductor. The power loss analysis is conducted, as shown in Figure 12.

It can be seen from Figure 12 that as the switching frequency increases, the output power of the traditional inverter decreases. In the proposed inverter, because of the injection current, the losses of the main circuit switches are larger than that in the traditional inverter. Although the loss of the proposed inverter is large, the output power does not change significantly with the increase of frequency and remains at a high level.

The efficiency of the inverter can be calculated as the ratio between its output to input power:

$$\eta = \frac{P_o}{P_{in}} = \frac{P_o}{P_o + P_{losses}} \quad (33)$$

Based on the above analysis, the efficiency of the inverter at different frequency can be drawn and is indicated in Figure 13.

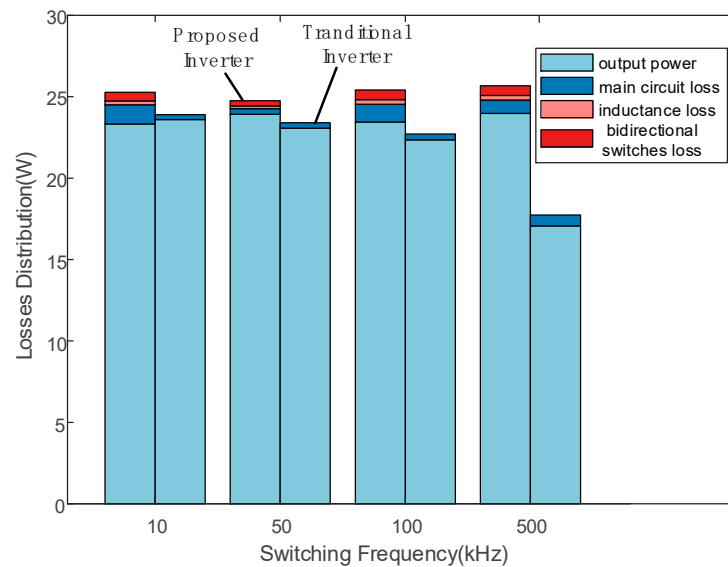


Figure 12. Comparison of power distribution in different frequencies.

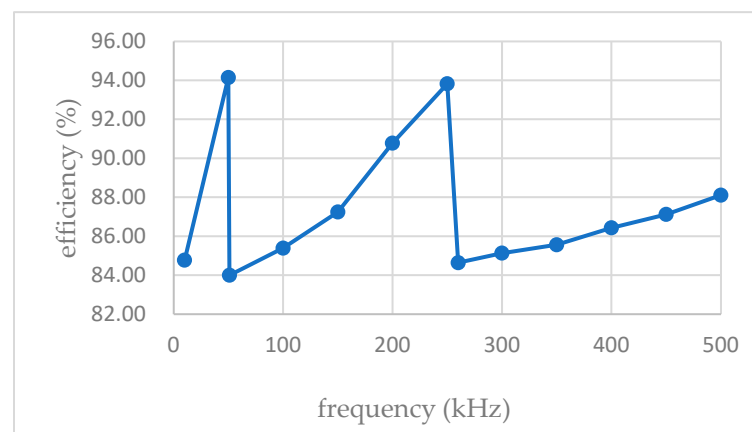


Figure 13. The efficiency of the inverter with variation in frequency.

With the frequency increases, the efficiency of the inverter increases within the corresponding region and decreases to about 84% at the critical frequency. The maximum efficiency can reach 94.14% from Figure 13. In each frequency range, with the increase of frequency, the time of current flowing through the auxiliary circuit elements decreases, and the loss decreases accordingly, the frequency will increase. When switching the number of the auxiliary circuit, the frequency is the lowest frequency of the group, so the time of current flowing is prolonged, resulting in reduced efficiency. Although the efficiency is reduced, the soft switching in a wide frequency domain can be realized, the electrical stress of the MOSFETS is reduced, and larger output power can be achieved.

3.4. Scalability to High Power Application

In order to study the scalability of the proposed architecture to large size high voltage converter, only the input voltage is increased to 400 V, and other conditions remain unchanged.

Taking the frequency of 50 kHz as an example, the load voltage and current waveforms are shown in Figure 14a; the trigger signals PWM1, PWM3 of the switch Q_1 , Q_3 , and the drain-source voltage waveform of the switch Q_1 are shown in Figure 14b; the trigger signals PWM2 and PWM4 of the switch Q_2 , Q_4 , and the drain-source voltage waveform of the switch Q_4 are shown in Figure 14c.

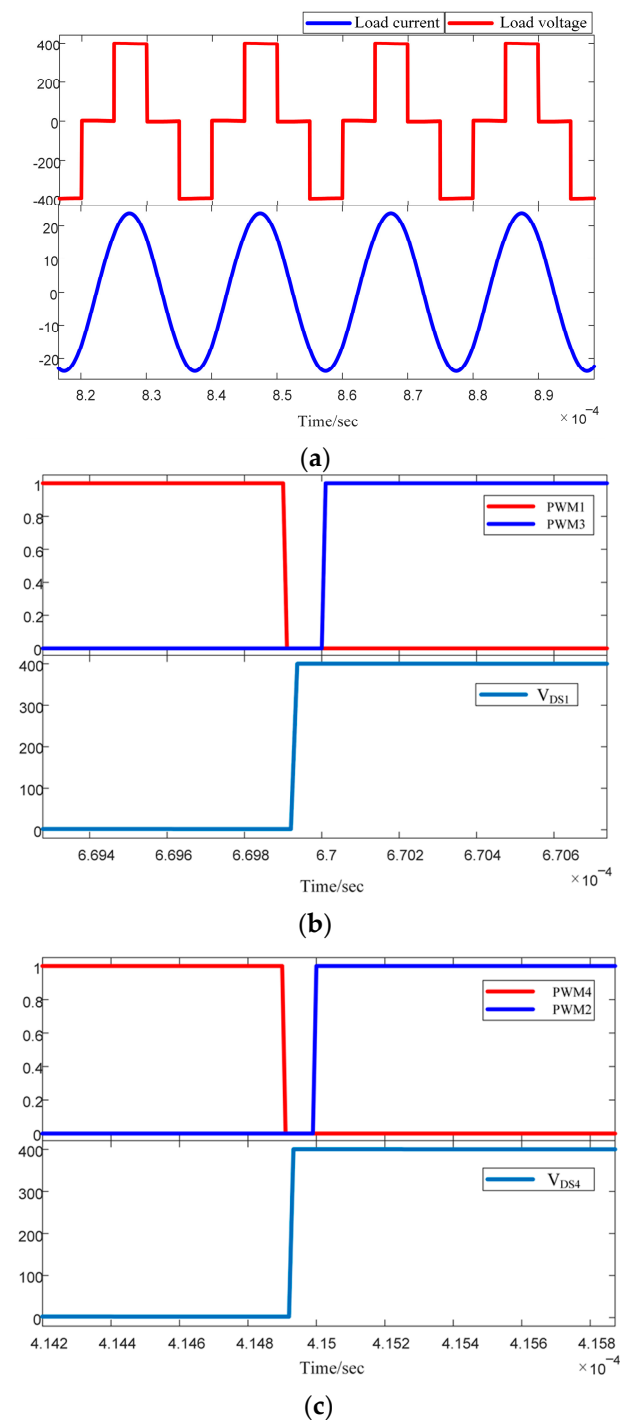


Figure 14. Main waveforms of the inverter under high power level. (a) Load voltage and current waveform; (b) Q_1Q_3 trigger signal and Q_1 drain-source voltage waveform; (c) Q_2Q_4 trigger signal and Q_4 drain-source voltage waveform.

It is obvious that the proposed inverter can still achieve soft switching under high power level, and the output power is 4.25 kW, the efficiency is 94.9%, which proves the scalability of the architecture.

4. Experimental Results and Analysis

To verify the ability of the proposed circuit to achieve soft switching within a certain frequency range, an experimental circuit board is now developed based on the circuit topology shown in Figure 6. Its parameters are shown in Table 2. In this experiment, due to

the limitation of laboratory conditions, the power level is not high, and efficiency is not the primary consideration. According to the different switching frequencies, the network parameters of each auxiliary current source are selected according to Table 1.

Table 2. Circuit component parameters.

Parameter	Value
power supply voltage V_{DC} (V)	30
Phase shift angle θ ($^\circ$)	90
Load inductance L (mH)	1
Load Resistance R (Ω)	15
Gate Signal Duty Cycle D (%)	50
MOSFET	NCE8290AC
Bidirectional switch	AOD482
ESR of the inductance L_{a1} (m Ω)	150
ESR of the inductance L_{a2} (m Ω)	55
ESR of the inductance L_{a3} (m Ω)	35
Auxiliary diode	SS510
Gate driver chip	UCC27712

4.1. Without Auxiliary Current Source

Without the auxiliary current source, the load voltage and current, and the related waveforms of the leading and lagging bridge arms of the basic PSFB topology at a switching frequency of 10 kHz are measured, as shown in Figure 15. It can be seen that when the load inductance and the load capacitor resonate in series, the drain-source voltage v_{ds3} of the leading bridge arm switch Q_3 has dropped to zero before the turn-on signal, indicating that the leading bridge arm can achieve zero-voltage soft switching. However, the lagging bridge arm switch Q_4 cannot discharge its parallel capacitor C_4 due to the reverse current, and its drain-source voltage v_{ds4} has not yet dropped to zero when the turn-on signal comes, which leads to hard switching and the waveform of the load voltage shows an obvious overshoot.

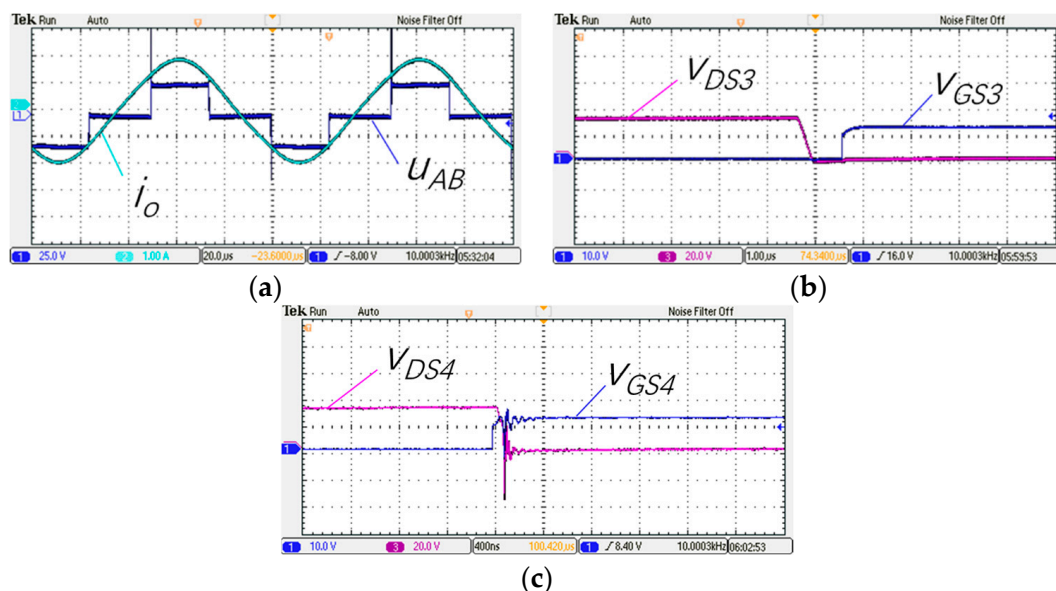


Figure 15. The relevant waveforms without auxiliary current source. (a) Load voltage and current waveforms; (b) Q_3 trigger signal and Q_3 drain-source voltage waveform; (c) Q_4 trigger signal and Q_4 drain-source voltage waveform.

4.2. With Auxiliary Current Source

With the auxiliary current source, the load voltage and current, the current injected by the auxiliary current source, and the related waveforms of the leading and lagging bridge arms at 10 kHz are measured, as shown in Figure 16.

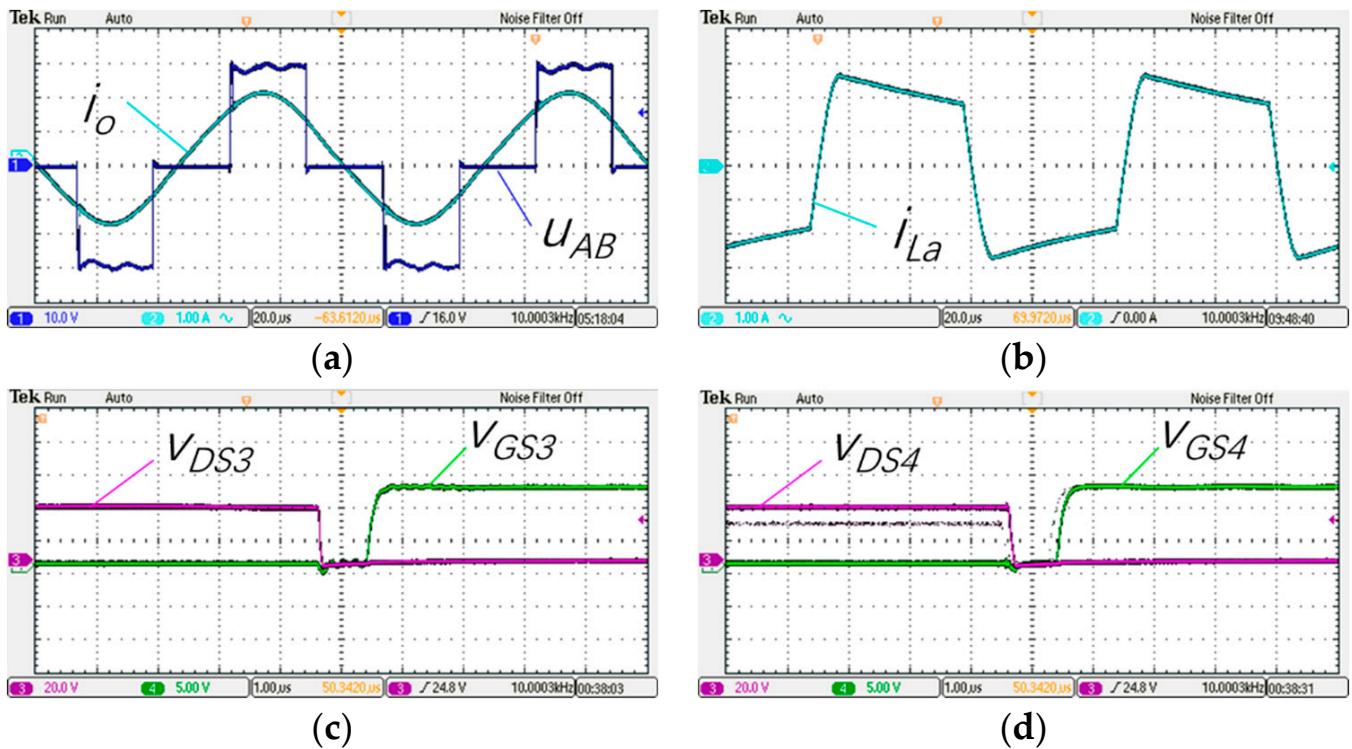


Figure 16. The relevant waveforms with auxiliary current source. (a) Load voltage and current waveforms; (b) Injection current waveform; (c) Q_3 trigger signal and Q_3 drain-source voltage waveform; (d) Q_4 trigger signal and Q_4 drain-source voltage waveform.

It can be seen from the figure that the leading bridge arm can still achieve zero-voltage soft switching, and the drain-source voltage v_{ds4} of the switch Q_4 can be discharged when the turn-on signal comes, and is completely discharged before the turn-on signal, indicating that the lagging bridge arm can also achieve zero-voltage soft switching due to the auxiliary current source. The current stresses of the auxiliary inductance and the auxiliary capacitor are 2.56 A, 1.52 A, which are lower than their respective current ratings of 3 A, 2 A. Additionally, the voltage stresses of the auxiliary inductance and the auxiliary capacitor are both the voltage of the source, i.e., 30 V. Because of the addition of an auxiliary current source, the overshoot of the load voltage is significantly alleviated.

4.3. Operation of the Broadband Auxiliary Current Source

Since the actual coil inductance has a higher equivalent series resistance at high frequency, the actual frequency range is selected as 10 kHz–200 kHz. In order to verify the soft switching capability of this topology in the 10 kHz–200 kHz broadband, the frequency of 50 kHz, 100 kHz and 200 kHz is selected as the test frequency points in this paper, and the relevant waveforms of the lagging bridge arm are measured to verify the capability of soft switching.

At each test frequency point, each auxiliary current source network is selected and the injected current at the corresponding operating frequency and the related waveforms of the lagging bridge arm are measured, and the results are shown in Figures 17–19, respectively.

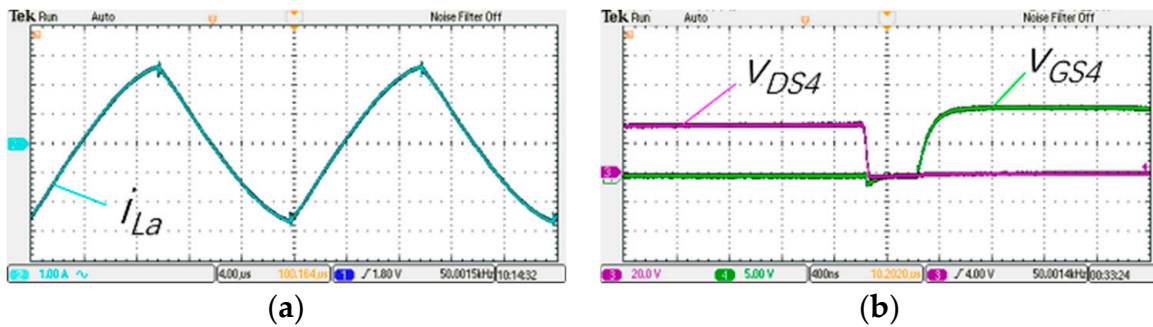


Figure 17. Injection current and lagging bridge arm waveform at 50 kHz. (a) Injection current; (b) Related waveform.

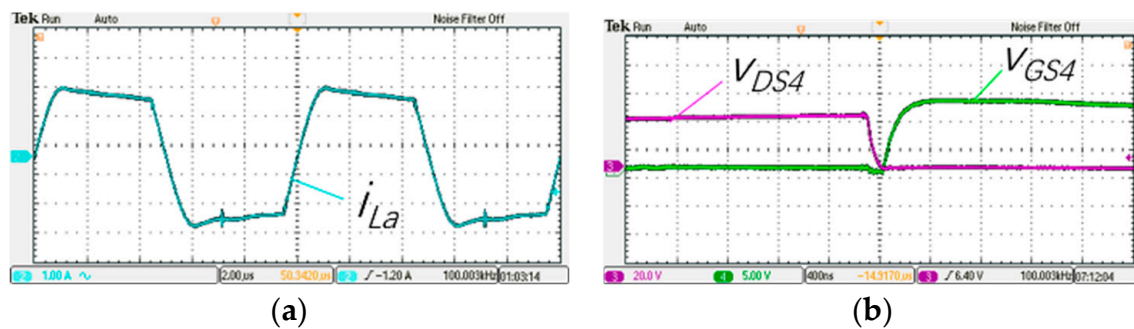


Figure 18. Injection current and lagging bridge arm waveform at 100 kHz. (a) Injection current; (b) Related waveform.

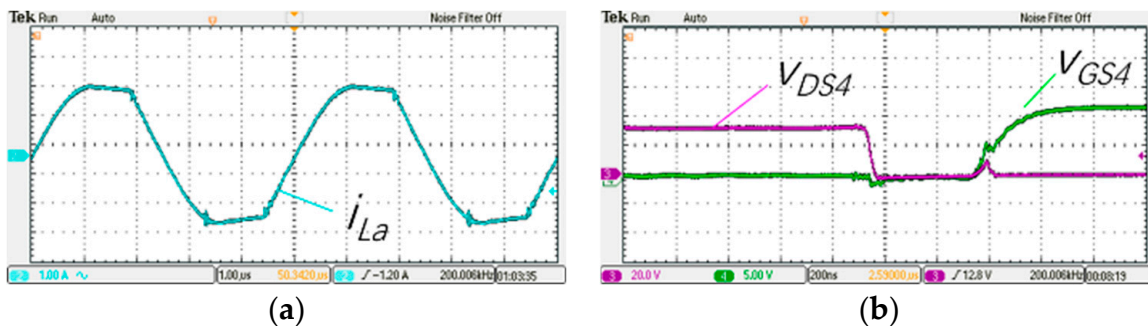


Figure 19. Injection current and lagging bridge arm waveform at 200 kHz. (a) Injection current; (b) Related waveform.

At each test frequency point, the selected auxiliary current source network parameters can ensure the zero-voltage soft switching of the lagging bridge arm at this frequency. By selecting each auxiliary current source network, zero-voltage soft-switching in the wide frequency range of 10 kHz–200 kHz can be realized.

5. Conclusions

In order to solve the problem of the current commutation in the lagging leg of full-bridge converter under broadband conditions, a current injection method is utilized in this paper, which can realize the function of soft switching of the lagging leg by injecting current into the lagging bridge arm. This paper analyses the influence of the injected current source on the circuit in different operating modes, gives the calculation method of the parameters of the auxiliary circuit adapted to different frequency ranges, analyses and discusses the influence of the auxiliary circuit on the power distribution of the converter. The feasibility of the scheme is verified by simulation and experiments. The results show that the load

power can fully meet the requirements of soft switching in the frequency range from 10 kHz to 200 kHz.

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